

CURRENT SENSE HIGH SIDE SWITCH

Features

- Suitable for 24V systems
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Reverse circulation immunization
- Optimized Turn On/Off for EMI
- Reverse battery protection (Mofset on)

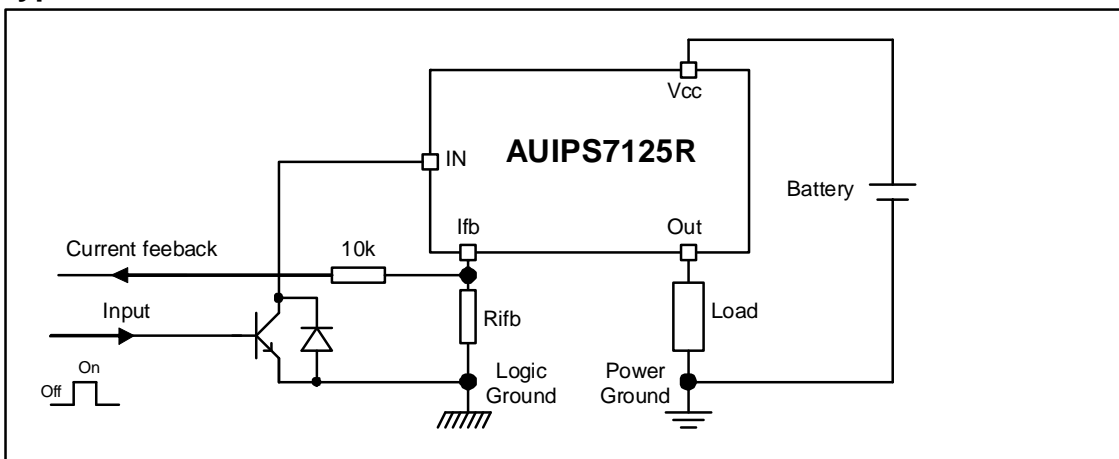
Applications

- 75W Filament lamp
- Solenoid
- 24V loads for trucks

Description

The AUIPS7125R is a fully protected five terminal high side switch specifically designed for driving lamp. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. When the input voltage $V_{cc} - V_{in}$ is higher than the specified threshold, the output power Mosfet is turned on. When the $V_{cc} - V_{in}$ is lower than the specified V_{il} threshold, the output Mosfet is turned off. The I_{fb} pin is used for current sensing. The over-current shutdown is higher than inrush current of the lamp.

Typical Connection



Product Summary

| | |
|------------------|-------------------|
| $R_{ds(on)}$ | 30m Ω max. |
| V_{clamp} | 65V |
| Current shutdown | 50A min. |

Packages



DPak

Qualification Information†

| | | | |
|-----------------------------------|----------------------|---|--|
| Qualification Level | | Automotive (per AEC-Q100††) | |
| | | Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level. | |
| Moisture Sensitivity Level | | DPAK-5L | MSL1, 260°C (per IPC/JEDEC J-STD-020) |
| ESD | Machine Model | Class M2 (200 V) (per AEC-Q100-003) | |
| | Human Body Model | Class H1C (1500 V) (per AEC-Q100-002) | |
| | Charged Device Model | Class C5 (1000 V) (per AEC-Q100-011) | |
| IC Latch-Up Test | | Class II, Level A (per AEC-Q100-004) | |
| RoHS Compliant | | Yes | |

† Qualification standards can be found at International Rectifier's web site <http://www.irf.com/>

†† Exceptions (if any) to AEC-Q100 requirements are noted in the qualification report.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. ($T_j = -40^{\circ}\text{C}..150^{\circ}\text{C}$, $V_{cc} = 6..50\text{V}$ unless otherwise specified).

| Symbol | Parameter | Min. | Max. | Units |
|--------------------------|--|-------------|--------------|--------------------|
| Vout | Maximum output voltage | $V_{cc}-60$ | $V_{cc}+0.3$ | V |
| I rev | Maximum reverse pulsed current ($t=100\mu\text{s}$) see page 8 | — | 60 | A |
| I _{sd} cont. | Maximum diode continuous current $T_{\text{ambient}}=25^{\circ}\text{C}$, $R_{\text{th}}=70^{\circ}\text{C}/\text{W}$ | — | 2.5 | |
| V _{cc-Vin} max. | Maximum V _{cc} voltage | -32 | 60 | V |
| I _{fb} , max. | Maximum feedback current | -50 | 10 | mA |
| V _{cc} sc | Maximum V _{cc} voltage with short circuit protection see page 8 | — | 50 | V |
| P _d | Maximum power dissipation (internally limited by thermal protection) $R_{\text{th}}=50^{\circ}\text{C}/\text{W}$ DPack 6cm ² footprint | — | 2.5 | W |
| T _j max. | Max. storage & operating junction temperature | -40 | 150 | $^{\circ}\text{C}$ |

Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Units |
|------------------|--|------|------|-----------------------------|
| R _{th1} | Thermal resistance junction to ambient DPak Std footprint | 70 | — | $^{\circ}\text{C}/\text{W}$ |
| R _{th2} | Thermal resistance junction to ambient Dpak 6cm ² footprint | 50 | — | |
| R _{th3} | Thermal resistance junction to case Dpak | 2 | — | |

Recommended Operating Conditions

These values are given for a quick design.

| Symbol | Parameter | Min. | Max. | Units |
|------------------|---|------|------|------------|
| I _{out} | Continuous output current, $T_{\text{ambient}}=85^{\circ}\text{C}$, $T_j=125^{\circ}\text{C}$ $R_{\text{th}}=50^{\circ}\text{C}/\text{W}$, Dpak 6cm ² footprint | — | 3.8 | A |
| R _{ifb} | I _{fb} resistor | 1.5 | — | k Ω |

Static Electrical Characteristics

T_j=-40°C..150°C, V_{cc}=6-50V (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|-------------------------|---|------|------|------|-------|--|
| V _{cc op.} | Operating voltage range | 6 | — | 60 | V | |
| R _{ds(on)} | ON state resistance T _j =25°C | — | 24 | 30 | mΩ | I _{ds} =2A |
| | ON state resistance T _j =150°C(2) | — | 45 | 55 | | |
| I _{cc off} | Supply leakage current | — | 2 | 4 | μA | V _{in} =V _{cc} =28V, V _{ifb} =V _{gnd} V _{out} =V _{gnd} , T _j =25°C |
| I _{out off} | Output leakage current | — | 2 | 4 | | |
| I _{in on} | Input current when device on | 1 | 3.5 | 6 | mA | V _{cc} -V _{in} =28V, T _j =25°C |
| V _{clamp1} | V _{cc} to V _{out} clamp voltage 1 | 60 | 64 | — | V | I _d =10mA |
| V _{clamp2} | V _{cc} to V _{out} clamp voltage 2 | 60 | 65 | 72 | | I _d =20A see fig. 2 |
| V _{ih(1)} | High level Input threshold voltage | — | 3.5 | 5.9 | | I _d =10mA |
| V _{il(1)} | Low level Input threshold voltage | 1.5 | 3.2 | — | | |
| R _{ds(on) rev} | Reverse On state resistance T _j =25°C | — | 25 | 40 | mΩ | I _{sd} =2A |
| V _f | Forward body diode voltage T _j =25°C | — | 0.75 | 0.85 | V | I _f =3A |
| | Forward body diode voltage T _j =125°C | — | 0.62 | 0.7 | | |
| R _{in} | Input resistor | 180 | 250 | 350 | Ω | |

(1) Input thresholds are measured directly between the input pin and the tab.

Switching Electrical Characteristics

V_{cc}=28V, Resistive load=6.8Ω, T_j=-40°C..150°C

| Symbol | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|-------------------|--|------|------|------|-------|-----------------|
| t _{don} | Turn on delay time | 5 | 15 | 30 | μs | See fig. 1 |
| t _r | Rise time from 20% to 80% of V _{cc} | 5 | 10 | 30 | | |
| t _{doff} | Turn off delay time | 35 | 75 | 120 | μs | |
| t _f | Fall time from 80% to 20% of V _{cc} | 6 | 15 | 30 | | |

Protection Characteristics

T_j=-40°C..150°C, V_{cc}=6-50V (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|--------------------|--|------|------|------|-------|------------------------|
| T _{sd} | Over temperature threshold(2) | 150 | 165 | — | °C | See fig. 3 and fig. 11 |
| I _{sd} | Over-current shutdown | 50 | 60 | 85 | A | See fig. 3 and page 7 |
| I _{fault} | I _{fb} after an over-current or an over-temperature (latched) | 2.2 | 3 | 5 | mA | See fig. 3 |

Current Sensing Characteristics

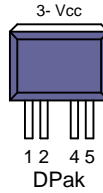
T_j=-40°C..150°C, V_{cc}=6-50V (unless otherwise specified). Specified 500μs after the turn on. V_{cc}-V_{ifb}>4V

| Symbol | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|-------------------------|---|-------|------|------|-------|---------------------------------|
| Ratio | I _{load} / I _{fb} current ratio | 7050 | 8500 | 9950 | | I _{load} <14A |
| Ratio_TC | I _{load} / I _{fb} variation over temperature(2) | -5% | 0 | +5 | % | T _j =-40°C to +150°C |
| I _{offset} | Load current offset | -0.06 | 0 | 0.06 | A | I _{out} <14A |
| I _{fb leakage} | I _{fb} leakage current | 0 | 1 | 10 | μA | I _{out} =0A |

(2) Guaranteed by design

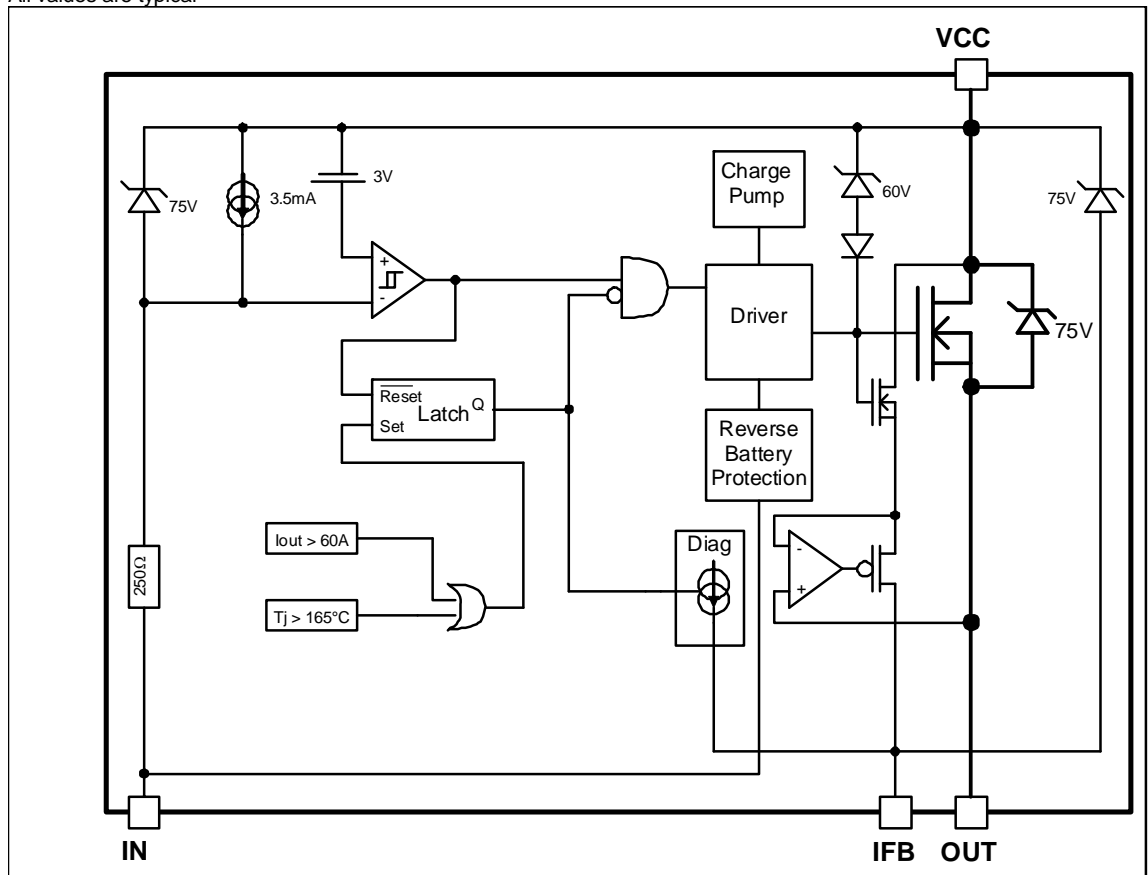
Lead Assignments

- 1- NC
- 2- In
- 3- Vcc
- 4- Ifb
- 5- Out



Functional Block Diagram

All values are typical



Truth Table

| Op. Conditions | Input | Output | I _{fb} pin voltage |
|----------------------|-------|--------|--|
| Normal mode | H | L | 0V |
| Normal mode | L | H | I _{load} x R _{fb} / Ratio |
| Open load | H | L | 0V |
| Open load | L | H | I _{fb} leakage x R _{fb} |
| Short circuit to GND | H | L | 0V |
| Short circuit to GND | L | L | I _{fault} x R _{fb} (latched) |
| Over temperature | H | L | 0V |
| Over temperature | L | L | I _{fault} x R _{fb} (latched) |

Operating voltage

Maximum V_{cc} voltage : this is the maximum voltage before the breakdown of the IC process.

Operating voltage : This is the V_{cc} range in which the functionality of the part is guaranteed. The AEC-Q100 qualification is run at the maximum operating voltage specified in the datasheet.

Reverse battery

During the reverse battery the Mosfet is turned on if the input pin is powered with a diode in parallel of the input transistor. Power dissipation in the IPS : $P = R_{ds(on)} \cdot I_{load}^2 + V_{cc}^2 / 250$ (internal input resistor).

If the power dissipation is too high in R_{fb}, a diode in serial can be added to block the current.

Active clamp

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.

The temperature increase during active clamp can be estimated as follows:

$$\Delta T_j = P_{CL} \cdot Z_{TH}(t_{CLAMP})$$

Where: $Z_{TH}(t_{CLAMP})$ is the thermal impedance at t_{CLAMP} and can be read from the thermal impedance curves given in the data sheets.

$P_{CL} = V_{CL} \cdot I_{CLavg}$: Power dissipation during active clamp

$V_{CL} = 65V$: Typical V_{CLAMP} value

$$I_{CLavg} = \frac{I_{CL}}{2} : \text{Average current during active clamp}$$

$$t_{CL} = \frac{I_{CL}}{\left| \frac{di}{dt} \right|} : \text{Active clamp duration}$$

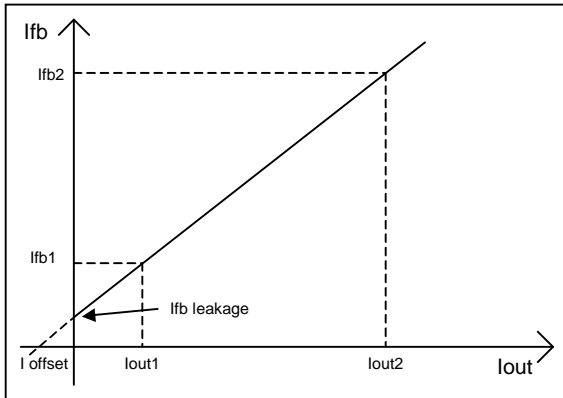
$$\frac{di}{dt} = \frac{V_{Battery} - V_{CL}}{L} : \text{Demagnetization current}$$

Figure 9 gives the maximum inductance versus the load current in the worst case : the part switches off after an over temperature detection. If the load inductance exceeds the curve, a free wheeling diode is required.

Over-current protection

The threshold of the over-current protection is set in order to guarantee that the device is able to turn on a load with an inrush current lower than the minimum of I_{sd}. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection. This behavior is shown in Figure 11.

Current sensing accuracy



The current sensing is specified by measuring 3 points :

- Ifb1 for Iout1
- Ifb2 for Iout2
- Ifb leakage for Iout=0

The parameters in the datasheet are computed with the following formula :

$$\text{Ratio} = (I_{out2} - I_{out1}) / (I_{fb2} - I_{fb1})$$

$$I_{offset} = I_{fb1} \times \text{Ratio} - I_{out1}$$

This allows the designer to evaluate the Ifb for any Iout value using :

$$I_{fb} = (I_{out} + I_{offset}) / \text{Ratio} \text{ if } I_{fb} > I_{fb \text{ leakage}}$$

For some applications, a calibration is required. In that case, the accuracy of the system will depend on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio_TC specified in page 4.

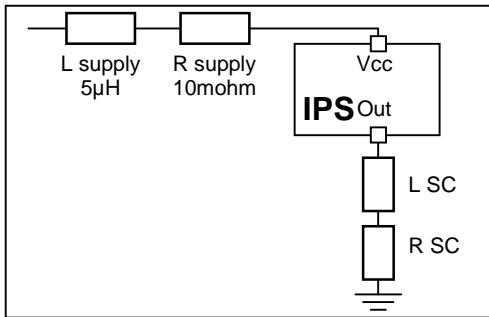
The I offset variation depends directly on the Rdson :

$$I_{offset@-40^{\circ}\text{C}} = I_{offset@25^{\circ}\text{C}} / 0.8$$

$$I_{offset@150^{\circ}\text{C}} = I_{offset@25^{\circ}\text{C}} / 1.9$$

Maximum Vcc voltage with short circuit protection

The maximum Vcc voltage with short circuit is the maximum voltage for which the part is able to protect itself under test conditions representative of the application. 2 kind of short circuits are considered : terminal and load short circuit.



| | L SC | R SC |
|-------------|--------|----------|
| Terminal SC | 0.1 µH | 10 mohm |
| Load SC | 10 µH | 100 mohm |

Maximum current during reverse circulation

In case of short circuit to battery, a voltage drop of the Vcc may create a current which circulate in reverse mode. When the device is on, this reverse circulation current will not trigger the internal fault latch. This immunization is also true when the part turns on while a reverse current flows into the device. The maximum current (I_{rev}) is specified in the maximum rating section.

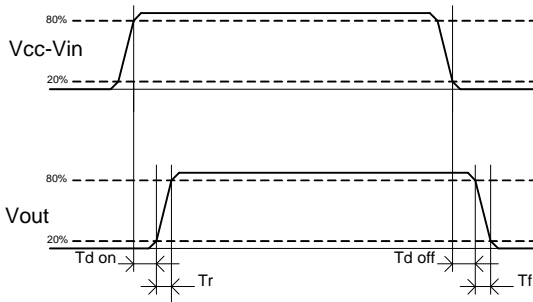
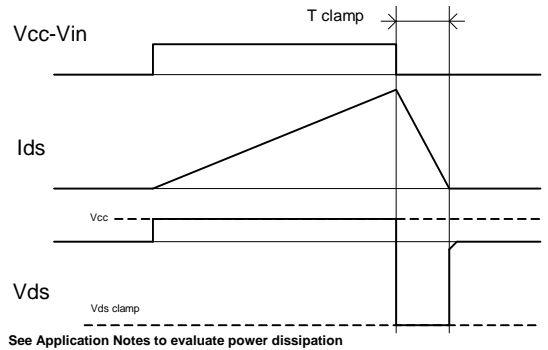


Figure 1 – IN rise time & switching definitions



See Application NOTES to evaluate power dissipation

Figure 2 – Active clamp waveforms

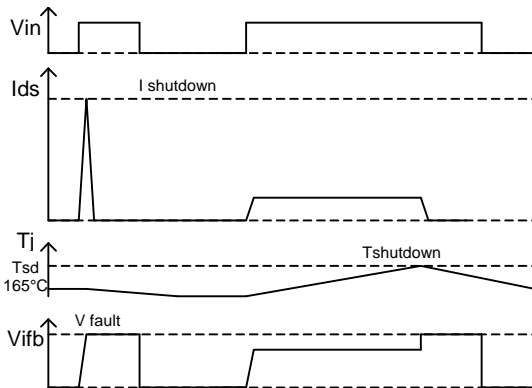


Figure 3 – Protection timing diagram

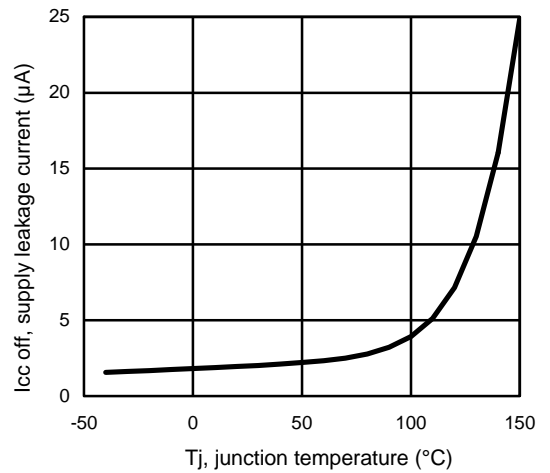


Figure 4 – Icc off (µA) Vs Tj (°C)

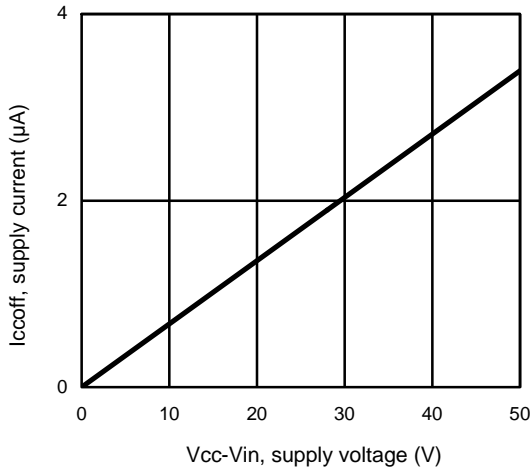


Figure 5 – Icc off(µA) Vs Vcc-Vin (V)

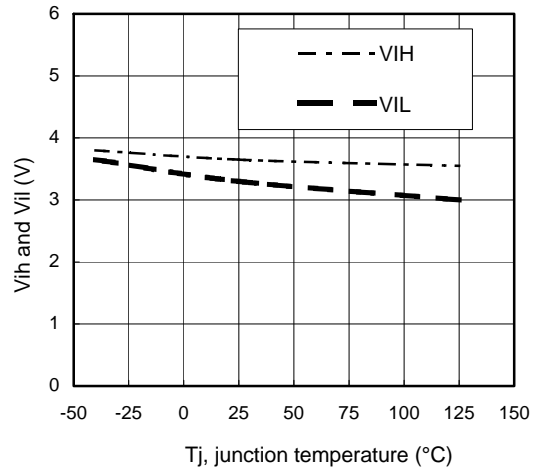


Figure 6 – Vih and Vil (V) Vs Tj (°C)

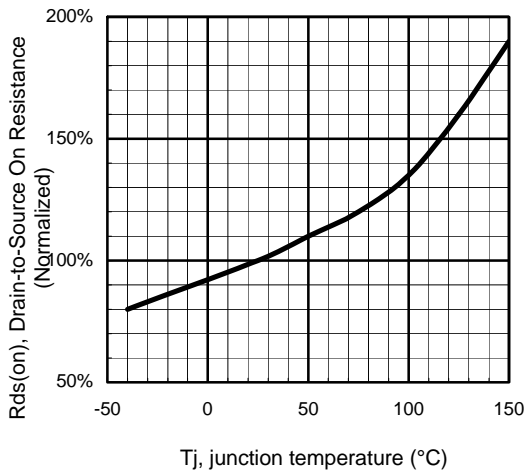


Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

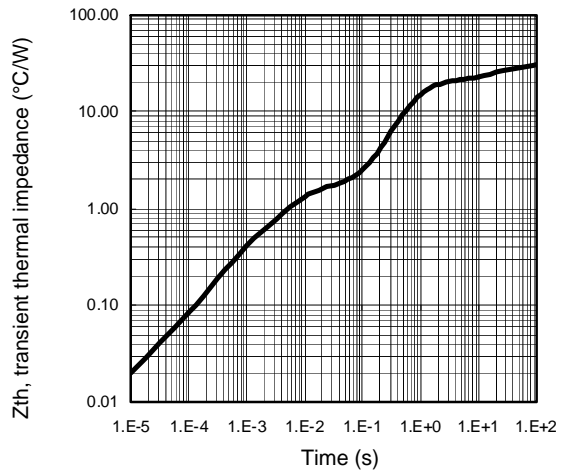


Figure 8 – Transient thermal impedance (°C/W) Vs time (s)

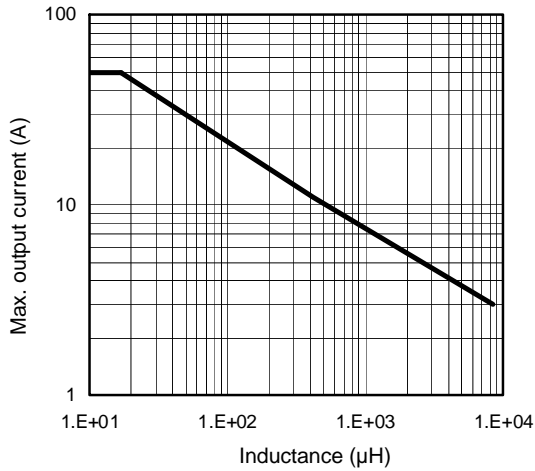


Figure 9 – Max. I_{out} (A) Vs inductance (µH)

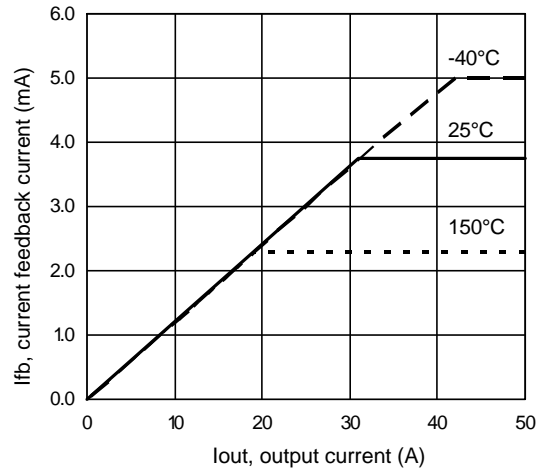
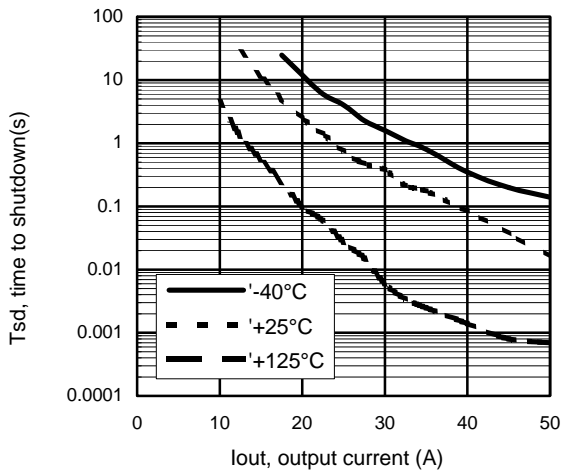
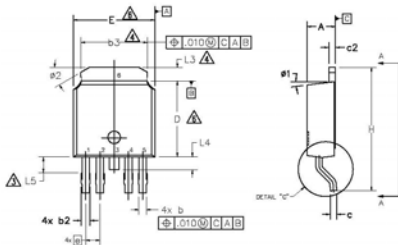
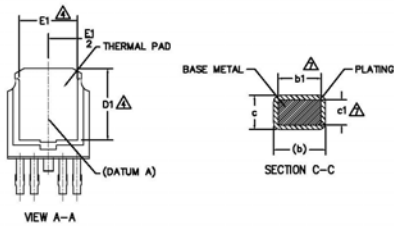
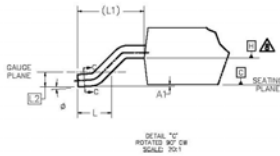


Figure 10 – I_{fb} (mA) Vs I_{out} (A)



**Figure 11 – Tsd (s) Vs I_{out} (A)
 SMD with 6cm²**

Case Outline 5 Lead – DPAK

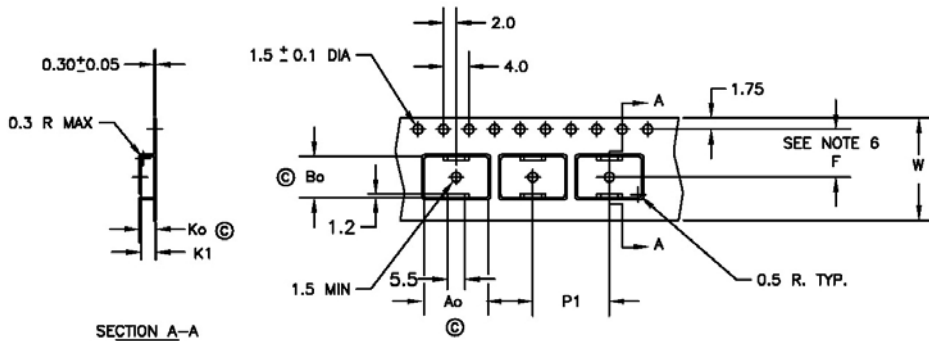


| SYMBOL | DIMENSIONS | | | | NOTES |
|--------|-------------|-------|-----------|------|-------|
| | MILLIMETERS | | INCHES | | |
| | MIN. | MAX. | MIN. | MAX. | |
| A | 2.18 | 2.39 | .086 | .094 | |
| A1 | — | 0.13 | — | .005 | |
| b | 0.56 | 0.79 | .022 | .031 | 2 |
| b1 | .056 | 0.74 | .022 | .029 | |
| b2 | 0.65 | 0.89 | .026 | .035 | |
| b3 | 4.95 | 5.46 | .195 | .215 | 2 |
| c | 0.46 | 0.61 | .018 | .024 | |
| c1 | 0.41 | 0.56 | .016 | .022 | 2 |
| c2 | 0.46 | 0.89 | .018 | .035 | |
| D | 5.97 | 6.22 | .235 | .245 | 3 |
| D1 | 5.21 | — | .205 | — | |
| E | 6.35 | 6.73 | .250 | .265 | 3 |
| E1 | 4.32 | — | .170 | — | |
| e | 1.14 BSC | | .045 BSC | | |
| H | 9.40 | 10.41 | .370 | .410 | |
| L | 1.40 | 1.78 | .055 | .070 | |
| L1 | 2.74 BSC | | .108 REF. | | |
| L2 | 0.51 BSC | | .020 BSC | | |
| L3 | 0.89 | 1.27 | .035 | .050 | |
| L4 | — | 1.02 | — | .040 | |
| L5 | 1.14 | 1.52 | .045 | .060 | |
| ø | 0" | 10" | 0" | 10" | |
| ø1 | 0" | 15" | 0" | 15" | |
| ø2 | 28" | 32" | 28" | 32" | |

NOTES:

- 1.— DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994
- 2.— DIMENSION ARE SHOWN IN INCHES [MILLIMETERS]
- △ LEAD DIMENSION UNCONTROLLED IN L5.
- △ DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.— SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- △ DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- △ DIMENSION b1 & c1 APPLIED TO BASE METAL ONLY.
- 8.— DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.— OUTLINE CONFORMS TO JEDEC OUTLINE TO-252.
10. LEADS AND DRAIN ARE PLATED WITH 100% Sn

Tape & Reel 5 Lead – DPAK

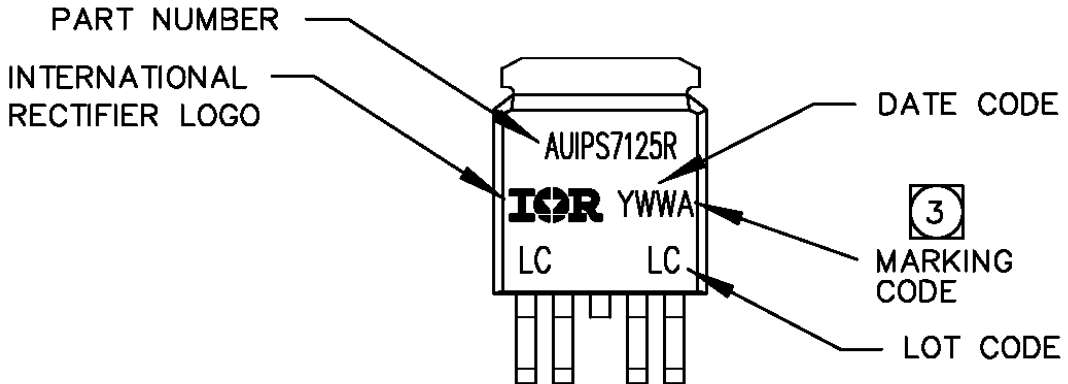


- Ao = 10.5 mm
- Bo = 7.0 mm
- Ko = 2.8 mm
- K1 = 2.4 mm
- F = 7.5 mm
- P1 = 12.0 mm
- W = 16.0 ± .3 mm

NOTES:

1. 10 SPROCKET HOLE PUNCH CUMULATIVE TOLERANCE ±.02
2. CAMBER NOT TO EXCEED 1mm IN 100mm
3. MATERIAL: CONDUCTIVE BLACK POLYSTYRENE
4. Ao AND Bo MEASURED ON A PLANE 0.3mm ABOVE THE BOTTOM OF THE POCKET
5. Ko MEASURED FROM A PLANE ON THE INSIDE BOTTOM OF THE POCKET TO THE TOP SURFACE OF THE CARRIER
6. POCKET POSITION RELATIVE TO THE SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE
7. VENDOR: (OPTIONAL)
8. MUST ALSO MEET REQUIREMENTS OF EIA STANDARD #EIA-481A, TAPING OF SURFACE-MOUNT COMPONENTS FOR AUTOMATIC PLACEMENT.
9. TOLERANCE TO BE MANUFACTURER STANDARD
10. SURFACE RESISTIVITY OF MOLDED MATL: MUST MEASURE LESS THAN OR EQUAL TO 10⁸ OHMS PER SQUARE. MEASURED IN ACCORDANCE TO PROCEDURE GIVEN IN ASTM D-257 & ASTM D-991 (REF. C-9000 SPEC.)
11. TOTAL LENGTH PER REEL MUST BE 79 METERS
12. © CRITICAL DIMENSION

Part Marking Information



Ordering Information

| Base Part Number | Package Type | Standard Pack | | Complete Part Number |
|------------------|--------------|---------------------|----------|----------------------|
| | | Form | Quantity | |
| AUIPS7125R | D-Pak-5-Lead | Tube | 75 | AUIPS7125R |
| | | Tape and reel | 2000 | AUIPS7125RTR |
| | | Tape and reel left | 3000 | AUIPS7125RTRL |
| | | Tape and reel right | 3000 | AUIPS7125RTRR |

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<http://www.irf.com/technical-info/>

WORLD HEADQUARTERS:

101 N Sepulveda Blvd., El Segundo, California 90245

Tel: (310) 252-7105

Revision History

| Revision | Date | Notes/Changes |
|-----------------|-------------|-----------------------------------|
| A1 | 08/03/2010 | |
| A2 | 29/04/2010 | Correct packing information |
| A3 | 07/09/2010 | Update current sensing capability |
| A4 | 31/05/2011 | Final release |
| A5 | 06/06/2011 | Update IR address |
| | | |
| | | |
| | | |
| | | |

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru